

8.0A FAST RECOVERY GLASS PASSIVATED RECTIFIER

FR801G – FR807G Vishaymas General Semiconductor

Features

- Glass Passivated Die Construction
- Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL
- Flammability Classification 94V-O

Mechanica Data

Case: Molded Plastic

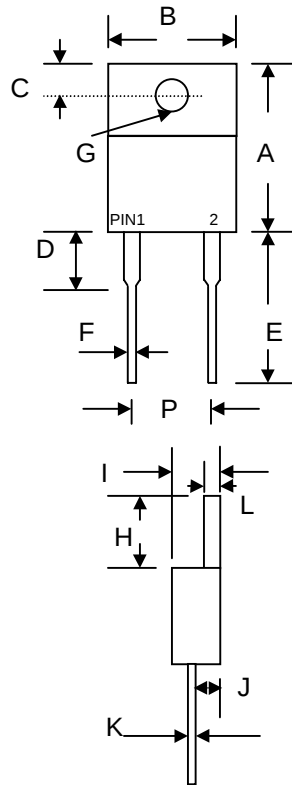
Terminals: Plated Leads Solderable
per MIL-STD-202, Method 208

Polarity: See Diagram

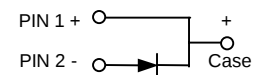
Weight: 2.24 grams (approx.)

Mounting Position: Any

Marking: Type Number



TO-220AC		
Dim	Min	Max
A	14.9	15.1
B	—	10.5
C	2.62	2.87
D	3.56	4.06
E	13.46	14.22
F	0.68	0.94
G	3.74 Ø	3.91 Ø
H	5.84	6.86
I	4.44	4.70
J	2.54	2.79
K	0.35	0.64
L	1.14	1.40
P	4.95	5.20
All Dimensions in mm		



Maximum Ratings and Electrical Characteristics

@T_A=25°C unless otherwise specified Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	FR 801G	FR 802G	FR 803G	FR 804G	FR 805G	FR 806G	FR 807G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current @T _C = 100°C	I _O	8.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150							A
Forward Voltage @I _F = 8.0A	V _{FM}	1.3							V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _{RM}	5.0 100							µA
Reverse Recovery Time (Note 1)	t _{rr}	150				250	500		nS
Typical Junction Capacitance (Note 2)	C _j	100							pF
Typical Thermal Resistance Junction to Case	R _{θJC}	3.0							K/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150							°C

Note: 1. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A. See figure 5.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

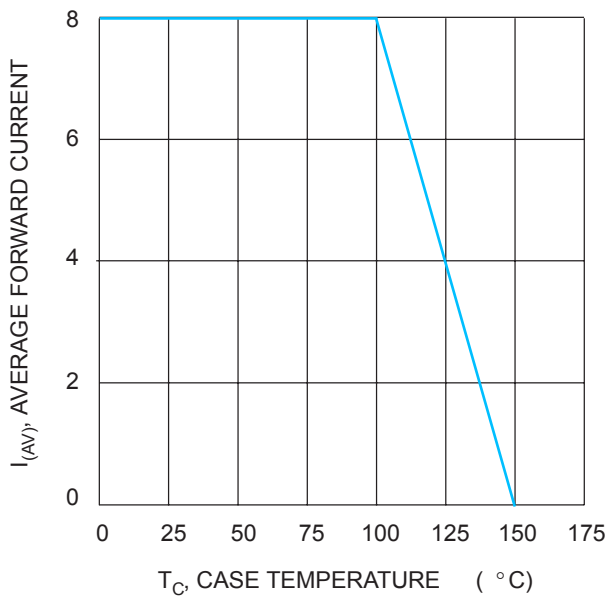


Fig. 1, Typical Forward Current Derating Curve

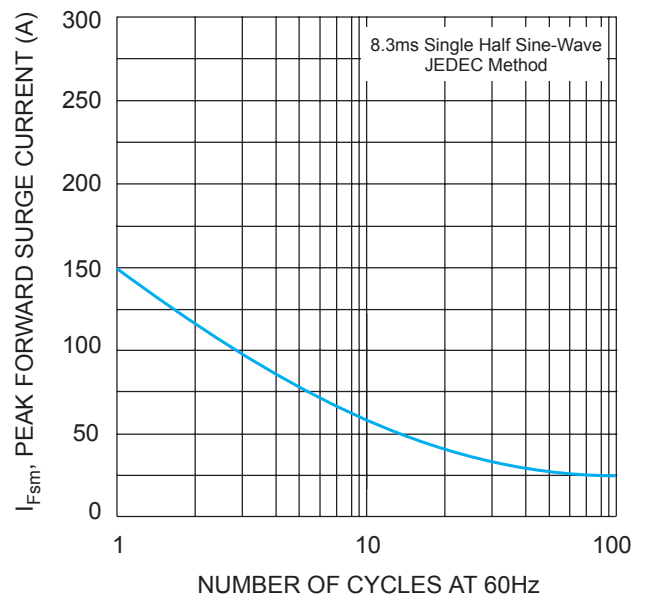


Fig. 2 Max Non-Repetitive Peak Surge Current

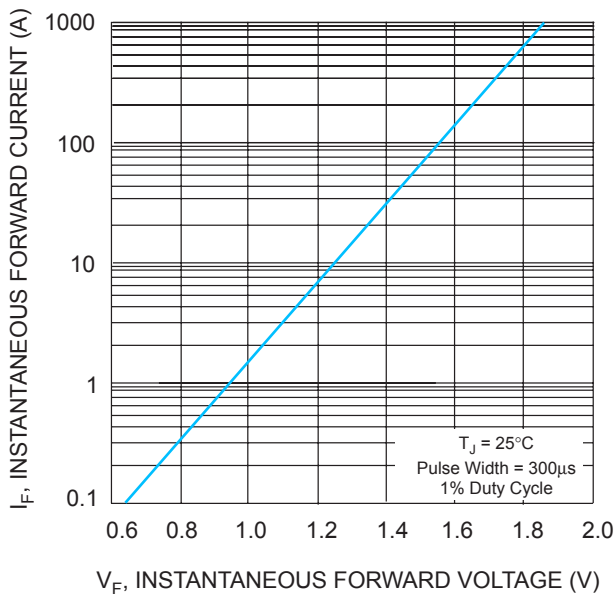


Fig. 3, Typical Instantaneous Forward Characteristics

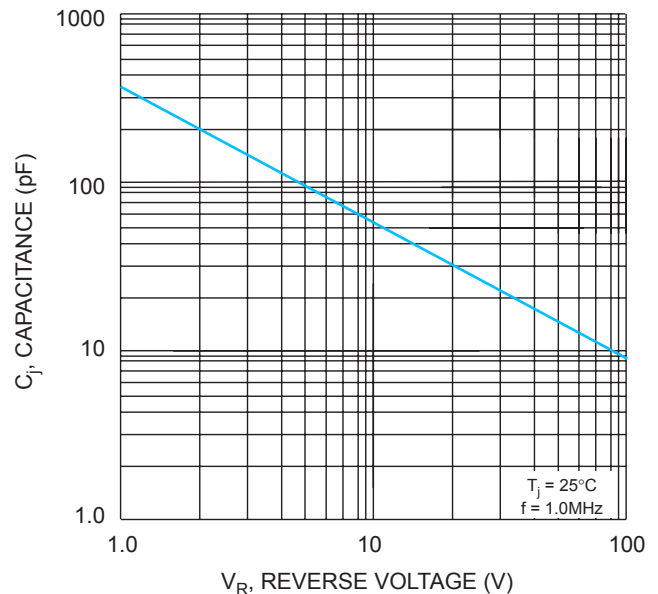
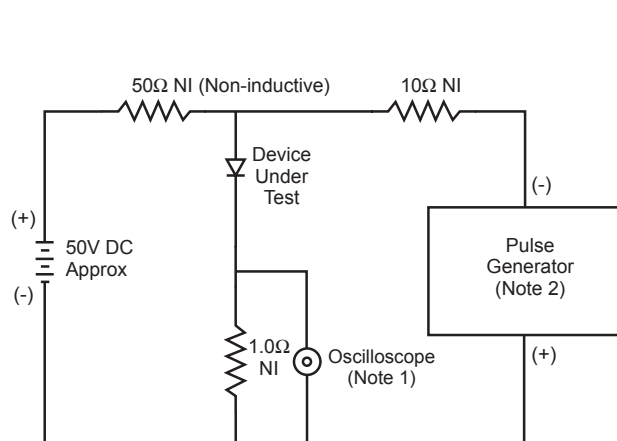
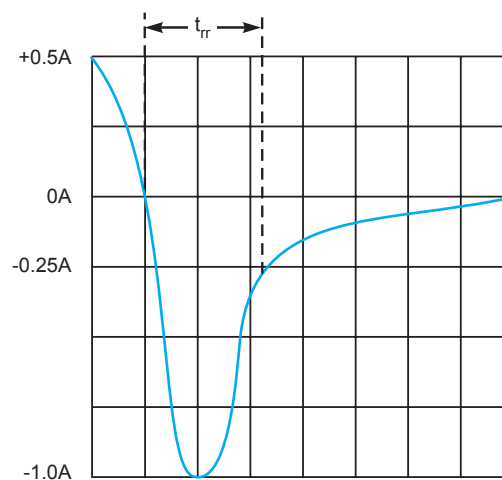


Fig. 4 Typical Junction Capacitance



Notes:

1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

